



A Product Line of Diodes Incorporated



120V NPN MEDIUM POWER DARLINGTON TRANSISTOR IN TO252

Features

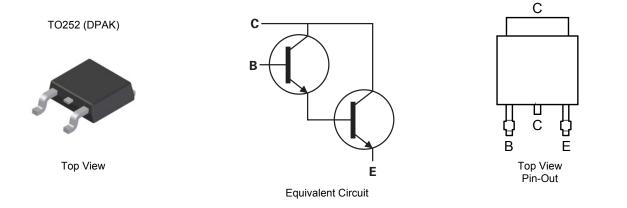
- BV_{CEO} > 120V
- BV_{CBO} > 140V
- I_C = 1.5A High Continuous current
- hFE > 2k for High Gain @ 1A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.34 grams (approximate)

Applications

- DC Fans
- Regulator Transistors
- Relays
- Solenoid Driving



Ordering Information (Note 4)

Product	Package	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN04120HKTC	TO252 (DPAK)	ZXTN04120H	13	16	2,500

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



ZXTN04120H = Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year, (ex: 13 = 2013) WW = Week Code 01 - 52





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	140	V
Collector-Emitter Voltage	V _{CEO}	120	V
Emitter-Base Voltage	V _{EBO}	14	V
Continuous Collector Current	lc	1.5	A
Peak Pulse Current	I _{CM}	4	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.9		
Power Dissipation	(Note 6)	PD	2	W	
	(Note 7)		1.5]	
	(Note 5)		32		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R _{θJA}	62.5		
	(Note 7)		80	°C/W	
Thermal Resistance, Junction to Leads	(Note 8)	R _{θJL}	9		
Thermal Resistance, Junction to Case	(Note 9)	R _{ejc}	11		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	С°	

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

 For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
Same as note (5), except mounted on 25mm x 25mm 1oz copper. Notes:

7. Same as note (5), except mounted on minimum recommended pad (MRP) layout.

8. Thermal resistance from junction to solder-point (on the exposed collector pad).

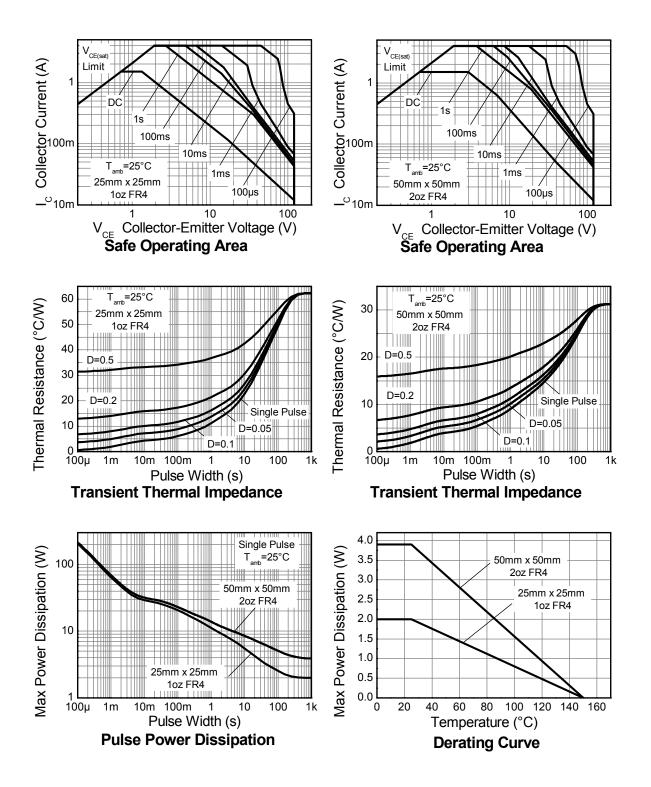
9. Thermal resistance from junction to the top of the case.

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information







Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

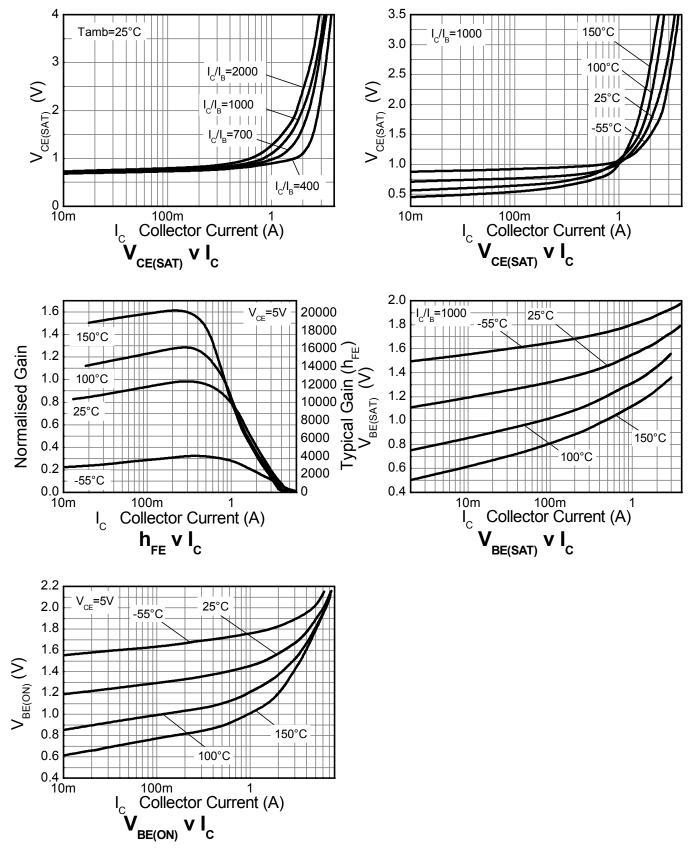
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	140	_	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	120	_	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	14	_	—	V	I _E = 100μA
Collector-Base Cutoff Current	I _{CBO}	_	_	100 10	nA μA	V _{CB} = 120V V _{CB} = 120V, T _A = +120°C
Collector-Emitter Cutoff Current	I _{CES}	-	-	100	nA	V _{CE} = 120V
Emitter Cutoff Current	I _{EBO}	_	_	100	nA	V _{EB} = 8V
DC Current Gain (Note 11)	h _{FE}	2,000 5,000 2,000 500	 	 100,000 	_	$I_{C} = 50mA, V_{CE} = 5V$ $I_{C} = 500mA, V_{CE} = 5V$ $I_{C} = 1A, V_{CE} = 5V$ $I_{C} = 2A, V_{CE} = 5V$
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}			1 1.5	V	I _C = 250mA, I _B = 0.25mA I _C = 1A, I _B = 1mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	_		1.8	V	I _C = 1A, I _B = 1mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	_	_	1.7	V	I _C = 1A, V _{CE} = 5V
Input Capacitance (Note 11)	Cibo		90	_	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance (Note 11)	Cobo	_	15	—	pF	V _{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product (Note 11)	fT	150	_	_	MHz	V _{CE} = 10V, I _C = 100mA, f=20MHz
Turn-On Time	t _{on}	_	0.5	_	μs	V _{CC} = 10V, I _C = 500mA
Turn-Off Time	t _{off}	_	1.6	_	μs	$I_{B1} = -I_{B2} = 0.5 \text{mA}$

Note: 11. Measured under pulsed conditions. Pulse width \leq 300 µs. Duty cycle \leq 2%.



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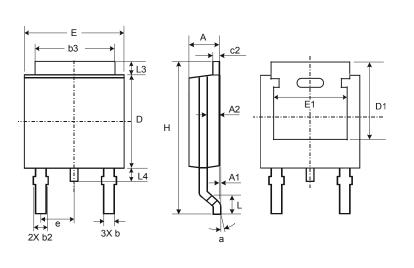
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

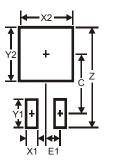
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	TO252					
Dim	Min	Max	Тур			
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
c2	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21	-	-			
е	-	-	2.286			
Ε	6.45	6.70	6.58			
E1	4.32	_	-			
Н	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
С	6.9
E1	2.3

Note: 12. For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



ZXTN04120HK

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